6 A High-Speed MOSFET Drivers

The NCP4420/NCP4429 are 6 A (peak), single output, MOSFET drivers. The NCP4429 is an inverting driver while the NCP4420 is a non–inverting driver. These drivers are fabricated in CMOS for lower power and more efficient operation versus bipolar drivers.

Both drivers have TTL–compatible inputs, which can be driven as high as $V_{DD}+0.3~V$ or as low as -5~V without upset or damage to the device. This eliminates the need for external level shifting circuitry and its associated cost and size. The output swing is rail–to–rail ensuring better drive voltage margin, especially during power up/power down sequencing. Propagational delay time is only 55 nsec (typ.) and the output rise and fall times are only 25 nsec (typ.) into 2500 pF across the useable power supply range.

Unlike other drivers, the NCP4420/NCP4429 are virtually latch—up proof. They can replace three or more discrete components saving PCB area, costs and improving overall system reliability.

Features

- Latch–Up Protected: Will Withstand > 1.5 A Reverse Output Current
- Logic Input Will Withstand Negative Swing Up to 5 V
- ESD Protected (4 kV)
- Matched Rise and Fall Times (25 nsec)
- High Peak Output Current (6 A Peak)
- Wide Operating Range (4.5 V to 18 V)
- High Capacitive Load Drive (10,000 pF)
- Short Delay Time (55 nsec Typ)
- Logic High Input, any Voltage (2.4 V to V_{DD})
- Low Supply Current with Logic "1" Input (450 μA)
- Low Output Impedance (2.5 Ω)
- Output Voltage Swing to within 25 mV of Ground or VDD
- Temperature Range –40°C to +85°C

Applications

- Switch–Mode Power Supplies
- Motor Controls
- Pulse Transformer Driver
- Class D Switching Amplifiers



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MARKING DIAGRAM



SO-8 D SUFFIX CASE 751





PDIP-8 P SUFFIX CASE 626



= Device Number (0 or 9)

YY, Y = Year

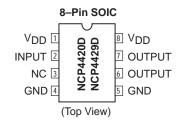
WW = Work Week

X = Assembly ID Code

Z = Subcontractor ID Code

CO = Country of Orgin

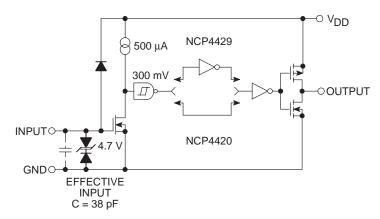
PIN CONNECTIONS



ORDERING INFORMATION

| Device | Package | Shipping |
|-----------------------------|---------|------------------|
| NCP4420DR2 Non–Inverting | SO-8 | 2500 Tape & Reel |
| NCP4429DR2 Inverting | SO-8 | 2500 Tape & Reel |
| NCP4420P Non-Inverting | PDIP-8 | 50 Units/Rail |
| NCP4429P Inverting | PDIP-8 | 50 Units/Rail |

FUNCTIONAL BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS*

| Rating | Value | Unit |
|--|-------------------------|-------|
| Supply Voltage | +20 | V |
| Input Voltage | −5.0 to V _{DD} | V |
| Input Current (V _{IN} > V _{DD}) | 50 | mA |
| Power Dissipation, $T_A \le 70^{\circ}C$ SOIC PDIP | 470 730 | mW |
| Derating Factors (To Ambient) SOIC PDIP | 4.0 8.0 | mW/°C |
| Storage Temperature Range, T _{Stg} | -65 to +150 | °C |
| Operating Temperature (Chip) | +150 | °C |
| Operating Temperature Range (Ambient), TA | -40 to +85 | °C |
| Lead Temperature (Soldering, 10 sec) | +300 | °C |

^{*}Static—sensitive device. Unused devices must be stored in conductive material. Protect devices from static discharge and static fields. Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS (T_A = +25°C with 4.5 V \leq V_{DD} \leq 18 V, unless otherwise specified.)

| Characteristic | Symbol | Test Conditions | Min | Тур | Max | Unit |
|----------------------------|-----------------------|---|------------------------|-----|----------------------|------|
| Input | | | | | | |
| Logic 1 High Input Voltage | VIH | - | 2.4 | 1.8 | _ | V |
| Logic 0 Low Input Voltage | V _{IL} | - | - | 1.3 | 0.8 | V |
| Input Voltage Range | V _{IN} (Max) | - | -5.0 | - | V _{DD} +0.3 | V |
| Input Current | IN | $0 \text{ V} \leq \text{V}_{IN} \leq \text{V}_{DD}$ | -10 | - | 10 | μΑ |
| Output | • | | | | | |
| High Output Voltage | Voн | See Figure 1 | V _{DD} -0.025 | _ | _ | V |
| Low Output Voltage | V _{OL} | See Figure 1 | - | - | 0.025 | V |
| Output Resistance, High | R _{OH} | I _{OUT} = 10 mA, V _{DD} = 18 V | - | 2.1 | 2.8 | Ω |
| Output Resistance, Low | R _{OL} | I _{OUT} = 10 mA, V _{DD} = 18 V | _ | 1.5 | 2.5 | Ω |

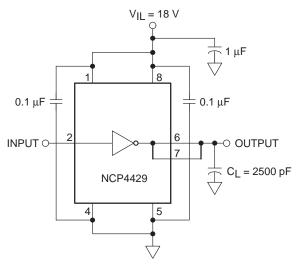
| Characteristic | Symbol | Test Conditions | Min | Тур | Max | Unit |
|---|-----------------|--|-----|------------|------------|----------|
| Output | | • | | • | | |
| Peak Output Current | lPK | V _{DD} = 18 V (See Figure 5) | - | 6.0 | _ | А |
| Latch–Up Protection Withstand Reverse Current | IREV | Duty Cycle ≤ 2% t ≤ 300 μs | 1.5 | _ | - | А |
| Switching Time (Note 1.) | | • | | • | | |
| Rise Time | t _R | Figure 1, C _L = 2500 pF | _ | 25 | 35 | nsec |
| Fall Time | tF | Figure 1, C _L = 2500 pF | _ | 25 | 35 | nsec |
| Delay Time 1 | t _{D1} | Figure 1 | _ | 55 | 75 | nsec |
| Delay Time 2 | t _{D2} | Figure 1 | - | 55 | 75 | nsec |
| Power Supply | | | | | | |
| Power Supply Current | IS | V _{IN} = 3.0 V V _{IN} = 0 V | - | 0.45 55 | 1.5 150 | mA μA |
| Operating Input Voltage | V _{DD} | _ | 4.5 | _ | 18 | V |

^{1.} Switching times guaranteed by design.

ELECTRICAL CHARACTERISTICS (Measured over operating temperature range with 4.5 V \leq V_{DD} \leq 18 V, unless otherwise specified.)

| Characteristic | Symbol | Test Conditions | Min | Тур | Max | Unit |
|----------------------------|-----------------------|---|------------------------|------------|----------------------|----------|
| Input | • | | | | | |
| Logic 1 High Input Voltage | VIH | _ | 2.4 | _ | - | V |
| Logic 0 Low Input Voltage | V _I L | _ | - | - | 0.8 | V |
| Input Voltage Range | V _{IN} (Max) | - | -5.0 | - | V _{DD} +0.3 | V |
| Input Current | IIN | $0 \text{ V} \leq \text{V}_{\text{IN}} \leq \text{V}_{\text{DD}}$ | -10 | - | 10 | μΑ |
| Output | · | | | | | |
| High Output Voltage | Voн | See Figure 1 | V _{DD} -0.025 | _ | _ | V |
| Low Output Voltage | VOL | See Figure 1 | _ | _ | 0.025 | V |
| Output Resistance, High | ROH | I _{OUT} = 10 mA, V _{DD} = 18 V | - | 3.0 | 5.0 | Ω |
| Output Resistance, Low | R _{OL} | I _{OUT} = 10 mA, V _{DD} = 18 V | - | 2.3 | 5.0 | Ω |
| Switching Time (Note 1.) | • | • | | | | |
| Rise Time | t _R | Figure 1, C _L = 2500 pF | - | 32 | 60 | nsec |
| Fall Time | tF | Figure 1, C _L = 2500 pF | _ | 34 | 60 | nsec |
| Delay Time 1 | t _{D1} | Figure 1 | _ | 50 | 100 | nsec |
| Delay Time 2 | t _{D2} | Figure 1 | - | 65 | 100 | nsec |
| Power Supply | · | | | | | |
| Power Supply Current | IS | V _{IN} = 3.0 V V _{IN} = 0 V | | 0.45 60 | 3.0 400 | mA μA |
| Operating Input Voltage | V _{DD} | - | 4.5 | - | 18 | V |

^{1.} Switching times guaranteed by design.



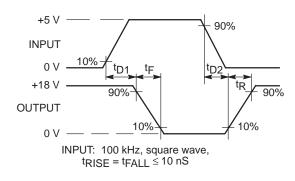


Figure 1. Switching Time Test Circuit

TYPICAL CHARACTERISTICS

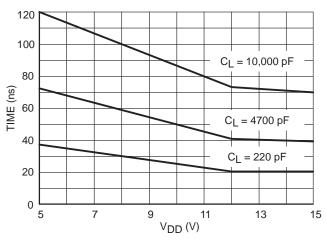


Figure 2. Rise Time vs. Supply Voltage

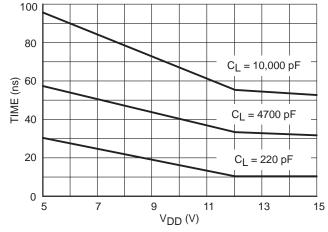


Figure 3. Fall Time vs. Supply Voltage

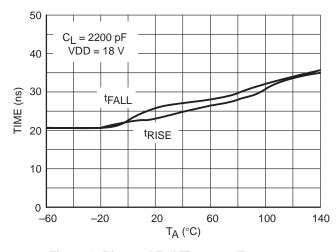


Figure 4. Rise and Fall Times vs. Temperature

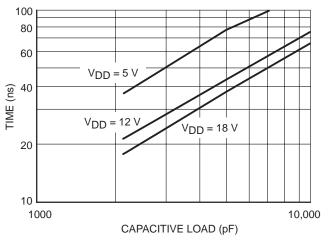


Figure 5. Rise Time vs. Capacitive Load

TYPICAL CHARACTERISTICS

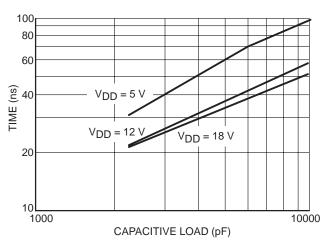


Figure 6. Fall Time vs. Capacitive Load

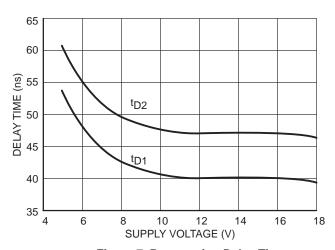


Figure 7. Propagation Delay Time vs.Supply Voltage

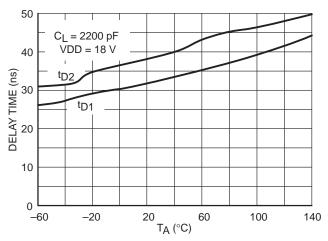


Figure 8. Propagation Delay Time vs. Temperature

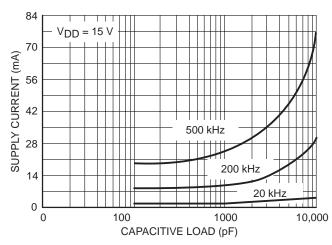


Figure 9. Supply Current vs. Capacitive Load

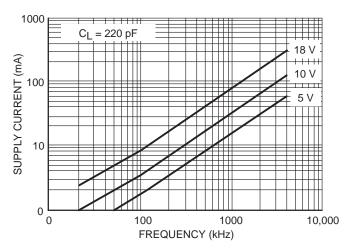


Figure 10. Supply Current vs. Frequency

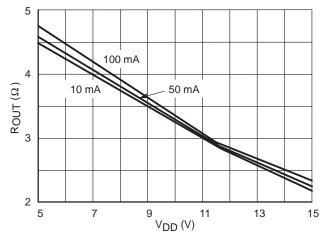
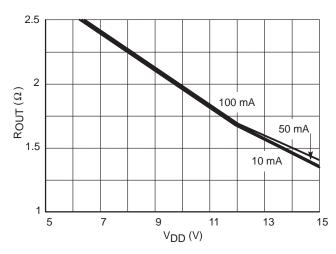


Figure 11. High-State Output Resistance

TYPICAL CHARACTERISTICS



200 LOAD = 2200 pF 160 DELAY TIME (ns) INPUT 2.4 V INPUT 3 V 80 INPUT 5 V 40 INPUT 8 V AND 10 V 5 6 7 8 9 10 11 12 13 15 $V_{DD}(V)$

Figure 12. Low-State Output Resistance

Figure 13. Effect of Input Amplitude on Propagation Delay

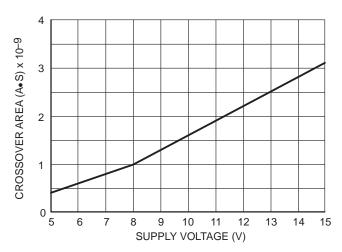
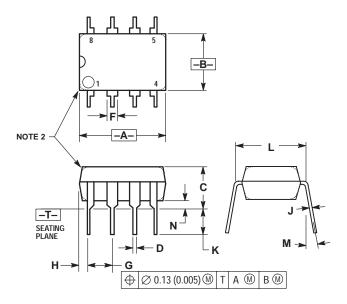


Figure 14. Total nA•S Crossover*

^{*} The values on this graph represent the loss seen by the driver during one complete cycle. For a single transition, divide the value by 2.

PACKAGE DIMENSIONS

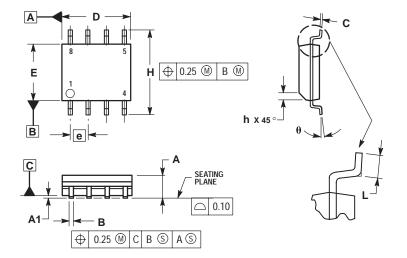
PDIP-8 **P SUFFIX** CASE 626-05 ISSUE K



- NOTES:
 1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
 2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

| | MILLIMETERS | | INC | HES |
|-----|-------------|-------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 9.40 | 10.16 | 0.370 | 0.400 |
| В | 6.10 | 6.60 | 0.240 | 0.260 |
| С | 3.94 | 4.45 | 0.155 | 0.175 |
| D | 0.38 | 0.51 | 0.015 | 0.020 |
| F | 1.02 | 1.78 | 0.040 | 0.070 |
| G | 2.54 BSC | | 0.100 BSC | |
| Н | 0.76 | 1.27 | 0.030 | 0.050 |
| J | 0.20 | 0.30 | 0.008 | 0.012 |
| K | 2.92 | 3.43 | 0.115 | 0.135 |
| L | 7.62 BSC | | 0.300 | BSC |
| M | | 10° | | 10° |
| N | 0.76 | 1.01 | 0.030 | 0.040 |

SO-8 **D SUFFIX** CASE 751-06 ISSUE T



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 DIMENSIONS ARE IN MILLIMETER.
 DIMENSION DAND E DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

| | MULIMETERS | | | | |
|-----|-------------|------|--|--|--|
| | MILLIMETERS | | | | |
| DIM | MIN | MAX | | | |
| Α | 1.35 | 1.75 | | | |
| A1 | 0.10 | 0.25 | | | |
| В | 0.35 | 0.49 | | | |
| С | 0.19 | 0.25 | | | |
| D | 4.80 | 5.00 | | | |
| Ε | 3.80 | 4.00 | | | |
| е | 1.27 BSC | | | | |
| Н | 5.80 | 6.20 | | | |
| h | 0.25 | 0.50 | | | |
| L | 0.40 | 1.25 | | | |
| A | 0 ° | 7 0 | | | |

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